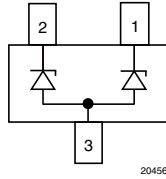
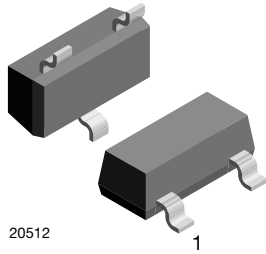


Two-Line ESD-Protection in SOT-23

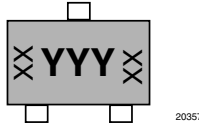


FEATURES

- Two-line ESD-protection device
- ESD-protection acc. IEC 61000-4-2
± 30 kV contact discharge
± 30 kV air discharge
- Space saving SOT-23 package
- AEC-Q101 qualified
- e3 - Sn
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



MARKING (example only)



YYY = type code (see table below)
XX = date code

ORDERING INFORMATION				
DEVICE NAME	ENVIRONMENTAL STATUS	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY
GSOT03C	Standard	GSOT03C-GS08	3000	15 000
	Green	GSOT03C-V-G-08		
GSOT04C	Standard	GSOT04C-GS08	3000	15 000
	Green	GSOT04C-V-G-08		
GSOT05C	Standard	GSOT05C-GS08	3000	15 000
	Green	GSOT05C-V-G-08		
GSOT08C	Standard	GSOT08C-GS08	3000	15 000
	Green	GSOT08C-V-G-08		
GSOT12C	Standard	GSOT12C-GS08	3000	15 000
	Green	GSOT12C-V-G-08		
GSOT15C	Standard	GSOT15C-GS08	3000	15 000
	Green	GSOT15C-V-G-08		
GSOT24C	Standard	GSOT24C-GS08	3000	15 000
	Green	GSOT24C-V-G-08		
GSOT36C	Standard	GSOT36C-GS08	3000	15 000
	Green	GSOT36C-V-G-08		

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	ENVIRONMENTAL STATUS	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
GSOT03C	SOT-23	03C	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		C1G	Green	8.1 mg			
GSOT04C	SOT-23	04C	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		C8G	Green	8.1 mg			
GSOT05C	SOT-23	05C	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		C2C	Green	8.1 mg			
GSOT08C	SOT-23	08C	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		C3G	Green	8.1 mg			
GSOT12C	SOT-23	12C	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		C4G	Green	8.1 mg			
GSOT15C	SOT-23	15C	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		C5G	Green	8.1 mg			
GSOT24C	SOT-23	24C	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		C6G	Green	8.1 mg			
GSOT36C	SOT-23	36C	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
		C7G	Green	8.1 mg			

ABSOLUTE MAXIMUM RATINGS GSOT03C				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{PPM}	30	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		30	A
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{PP}	369	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		504	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 30	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	°C
Storage temperature		T_{STG}	- 55 to + 150	°C

ABSOLUTE MAXIMUM RATINGS GSOT04C				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{PPM}	30	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		30	A
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{PP}	429	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		564	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 30	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	°C
Storage temperature		T_{STG}	- 55 to + 150	°C



ABSOLUTE MAXIMUM RATINGS GSOT05C				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{PPM}	30	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		30	A
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{PP}	480	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		612	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 30	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}C$
Storage temperature		T_{STG}	- 55 to + 150	$^{\circ}C$

ABSOLUTE MAXIMUM RATINGS GSOT08C				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{PPM}	18	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		18	A
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{PP}	345	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		400	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 30	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}C$
Storage temperature		T_{STG}	- 55 to + 150	$^{\circ}C$

ABSOLUTE MAXIMUM RATINGS GSOT12C				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{PPM}	12	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		12	A
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{PP}	312	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		337	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 30	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}C$
Storage temperature		T_{STG}	- 55 to + 150	$^{\circ}C$

ABSOLUTE MAXIMUM RATINGS GSOT15C				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{PPM}	8	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		8	A
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{PP}	345	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		400	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 30	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}C$
Storage temperature		T_{STG}	- 55 to + 150	$^{\circ}C$

ABSOLUTE MAXIMUM RATINGS GSOT24C				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{PPM}	5	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		5	A
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{PP}	235	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		240	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 30	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}C$
Storage temperature		T_{STG}	- 55 to + 150	$^{\circ}C$

ABSOLUTE MAXIMUM RATINGS GSOT36C				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{PPM}	3.5	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		3.5	A
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{PP}	248	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		252	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 30	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}C$
Storage temperature		T_{STG}	- 55 to + 150	$^{\circ}C$

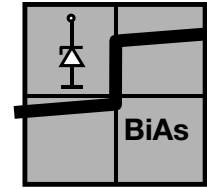
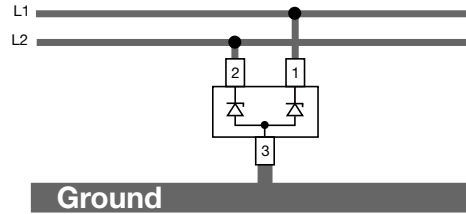
BiAs-MODE (2-line bidirectional asymmetrical protection mode)

With the GSOTxx one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 3 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V_{RWM}) the protection diode between pin 1 and pin 3 offer a high isolation to the ground line. The protection device behaves like an open switch.

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage (V_C) is defined by the breakthrough voltage (V_{BR}) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V_F) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the GSOTxx clamping behaviour is bidirectional and asymmetrical (BiAs).

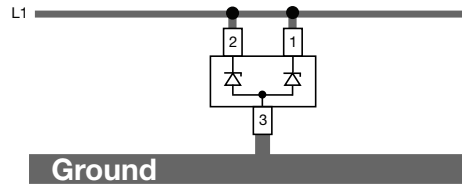


20358

If a higher surge current or peak pulse current (I_{PP}) is needed, both protection diodes in the GSOTxxC can also be used in parallel in order to “double” the performance.

This offers:

- double surge power = double peak pulse current ($2 \times I_{PPM}$)
- half of the line inductance = reduced clamping voltage
- half of the line resistance = reduced clamping voltage
- double line capacitance ($2 \times C_D$)
- double reverse leakage current ($2 \times I_R$)



20359

ELECTRICAL CHARACTERISTICS GSOT03C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	$N_{channel}$	-	-	2	lines
Reverse working voltage	at $I_R = 100 \mu A$	V_{RWM}	3.3	-	-	V
Reverse current	at $V_R = 3.3 V$	I_R	-	-	100	μA
Reverse breakdown voltage	at $I_R = 1 mA$	V_{BR}	4	4.6	-	V
Reverse clamping voltage	at $I_{PP} = 1 A$	V_C	-	5.7	7.5	V
	at $I_{PP} = I_{PPM} = 30 A$		-	10	12.3	V
Forward clamping voltage	at $I_{PP} = 1 A$	V_F	-	1	1.2	V
	at $I_{PP} = I_{PPM} = 30 A$		-	4.5	-	V
Capacitance	at $V_R = 0 V$; $f = 1 MHz$	C_D	-	420	600	pF
	at $V_R = 1.6 V$; $f = 1 MHz$		-	260	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 3 or pin 2 to 3)

ELECTRICAL CHARACTERISTICS GSOT04C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	$N_{channel}$	-	-	2	lines
Reverse working voltage	at $I_R = 20 \mu A$	V_{RWM}	4	-	-	V
Reverse current	at $V_R = 4 V$	I_R	-	-	20	μA
Reverse breakdown voltage	at $I_R = 1 mA$	V_{BR}	5	6.1	-	V
Reverse clamping voltage	at $I_{PP} = 1 A$	V_C	-	7.5	9	V
	at $I_{PP} = I_{PPM} = 30 A$		-	11.2	14.3	V
Forward clamping voltage	at $I_{PP} = 1 A$	V_F	-	1	1.2	V
	at $I_{PP} = I_{PPM} = 30 A$		-	4.5	-	V
Capacitance	at $V_R = 0 V$; $f = 1 MHz$	C_D	-	310	450	pF
	at $V_R = 2 V$; $f = 1 MHz$		-	200	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 3 or pin 2 to 3)

ELECTRICAL CHARACTERISTICS GSOT05C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	2	lines
Reverse working voltage	at $I_R = 10 \mu\text{A}$	V_{RWM}	5	-	-	V
Reverse current	at $V_R = 5 \text{ V}$	I_R	-	-	10	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	6	6.8	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	7	8.7	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 30 \text{ A}$		-	12	16	V
Forward clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_F	-	1	1.2	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 30 \text{ A}$		-	4.5	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	260	350	pF
	at $V_R = 2.5 \text{ V}$; $f = 1 \text{ MHz}$		-	150	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 3 or pin 2 to 3)

ELECTRICAL CHARACTERISTICS GSOT08C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	2	lines
Reverse working voltage	at $I_R = 5 \mu\text{A}$	V_{RWM}	8	-	-	V
Reverse current	at $V_R = 8 \text{ V}$	I_R	-	-	5	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	9	10	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	10.7	13	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 18 \text{ A}$		-	15.2	19.2	V
Forward clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_F	-	1	1.2	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 18 \text{ A}$		-	3	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	160	250	pF
	at $V_R = 4 \text{ V}$; $f = 1 \text{ MHz}$		-	80	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 3 or pin 2 to 3)

ELECTRICAL CHARACTERISTICS GSOT12C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	2	lines
Reverse working voltage	at $I_R = 1 \mu\text{A}$	V_{RWM}	12	-	-	V
Reverse current	at $V_R = 12 \text{ V}$	I_R	-	-	1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	13.5	15	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	15.4	18.7	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 12 \text{ A}$		-	21.2	26	V
Forward clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_F	-	1	1.2	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 12 \text{ A}$		-	2.2	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	115	150	pF
	at $V_R = 6 \text{ V}$; $f = 1 \text{ MHz}$		-	50	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 3 or pin 2 to 3)



ELECTRICAL CHARACTERISTICS GSOT15C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	2	lines
Reverse working voltage	at $I_R = 1 \mu\text{A}$	V_{RWM}	15	-	-	V
Reverse current	at $V_R = 15 \text{ V}$	I_R	-	-	1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	16.5	18	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	19.4	23.5	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 8 \text{ A}$		-	24.8	28.8	V
Forward clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_F	-	1	1.2	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 8 \text{ A}$		-	1.8	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	90	120	pF
	at $V_R = 7.5 \text{ V}$; $f = 1 \text{ MHz}$		-	35	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 3 or pin 2 to 3)

ELECTRICAL CHARACTERISTICS GSOT24C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	2	lines
Reverse working voltage	at $I_R = 1 \mu\text{A}$	V_{RWM}	24	-	-	V
Reverse current	at $V_R = 24 \text{ V}$	I_R	-	-	1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	27	30	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	34	41	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 5 \text{ A}$		-	41	47	V
Forward clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_F	-	1	1.2	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 5 \text{ A}$		-	1.4	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	65	80	pF
	at $V_R = 12 \text{ V}$; $f = 1 \text{ MHz}$		-	20	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 3 or pin 2 to 3)

ELECTRICAL CHARACTERISTICS GSOT36C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	2	lines
Reverse working voltage	at $I_R = 1 \mu\text{A}$	V_{RWM}	36	-	-	V
Reverse current	at $V_R = 36 \text{ V}$	I_R	-	-	1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	39	43	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	49	60	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 3.5 \text{ A}$		-	59	71	V
Forward clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_F	-	1	1.2	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 3.5 \text{ A}$		-	1.3	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	52	65	pF
	at $V_R = 18 \text{ V}$; $f = 1 \text{ MHz}$		-	12	-	pF

Note

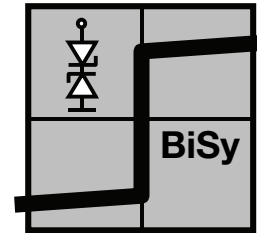
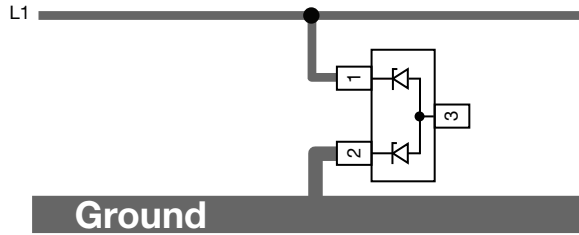
- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 3 or pin 2 to 3)

BiSy-MODE (1-line bidirectional symmetrical protection mode)

If a bipolar symmetrical protection device is needed the GSOTxxC can also be used as a single line protection device. Therefore pin 1 has to be connected to the signal- or data-line (L1) and pin 2 to ground (or vice versa). Pin 3 must not be connected.

Positive and negative voltage transients will be clamped in the same way. The clamping current through the GSOTxxC passes one diode in forward direction and the other one in reverse direction. The clamping voltage (V_C) is defined by the breakthrough voltage (V_{BR}) level of one diode plus the forward voltage of the other diode plus the voltage drop at the series impedances (resistances and inductances) of the protection device.

Due to the same clamping levels in positive and negative direction the GSOTxxC voltage clamping behaviour is bidirectional and symmetrical (BiSy).



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ELECTRICAL CHARACTERISTICS GSOT03C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_R = 100 \mu\text{A}$	V_{RWM}	3.8	-	-	V
Reverse current	at $V_R = 3.8 \text{ V}$	I_R	-	-	100	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	4.5	5.3	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	7	8.4	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 30 \text{ A}$		-	14	16.8	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	210	300	pF
	at $V_R = 1.6 \text{ V}$; $f = 1 \text{ MHz}$		-	190	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 2 or pin 2 to 1; pin 3 not connected)

ELECTRICAL CHARACTERISTICS GSOT04C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_R = 20 \mu\text{A}$	V_{RWM}	4.5	-	-	V
Reverse current	at $V_R = 4.5 \text{ V}$	I_R	-	-	20	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	5.5	6.8	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	7.5	9	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 30 \text{ A}$		-	15.7	18.8	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	155	225	pF
	at $V_R = 2 \text{ V}$; $f = 1 \text{ MHz}$		-	135	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 2 or pin 2 to 1; pin 3 not connected)

ELECTRICAL CHARACTERISTICS GSOT05C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_R = 10 \mu\text{A}$	V_{RWM}	5.5	-	-	V
Reverse current	at $V_R = 5.5 \text{ V}$	I_R	-	-	10	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	6.5	7.5	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	8.1	9.7	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 18 \text{ A}$		-	17	20.4	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	130	175	pF
	at $V_R = 4 \text{ V}$; $f = 1 \text{ MHz}$		-	100	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 2 or pin 2 to 1; pin 3 not connected)



ELECTRICAL CHARACTERISTICS GSOT08C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_R = 5 \mu\text{A}$	V_{RWM}	8.5	-	-	V
Reverse current	at $V_R = 8.5 \text{ V}$	I_R	-	-	5	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	9.5	10.7	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	11.7	14	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 18 \text{ A}$		-	18.5	22.2	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	80	125	pF
	at $V_R = 4 \text{ V}$; $f = 1 \text{ MHz}$		-	60	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 2 or pin 2 to 1; pin 3 not connected)

ELECTRICAL CHARACTERISTICS GSOT12C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_R = 1 \mu\text{A}$	V_{RWM}	12.5	-	-	V
Reverse current	at $V_R = 12.5 \text{ V}$	I_R	-	-	1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	13.5	15.7	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	16.4	19.7	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 12 \text{ A}$		-	23.4	28.1	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	58	75	pF
	at $V_R = 7.5 \text{ V}$; $f = 1 \text{ MHz}$		-	36	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 2 or pin 2 to 1; pin 3 not connected)

ELECTRICAL CHARACTERISTICS GSOT15C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_R = 1 \mu\text{A}$	V_{RWM}	15.5	-	-	V
Reverse current	at $V_R = 15.5 \text{ V}$	I_R	-	-	1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	17	18.7	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	20.4	24.5	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 8 \text{ A}$		-	26.6	30.6	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	45	60	pF
	at $V_R = 7.5 \text{ V}$; $f = 1 \text{ MHz}$		-	25	-	pF

Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 2 or pin 2 to 1; pin 3 not connected)

ELECTRICAL CHARACTERISTICS GSOT24C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_R = 1 \mu\text{A}$	V_{RWM}	24.5	-	-	V
Reverse current	at $V_R = 24.5 \text{ V}$	I_R	-	-	1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	27.5	30.7	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	34	41	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 5 \text{ A}$		-	40	48	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	33	40	pF
	at $V_R = 12 \text{ V}$; $f = 1 \text{ MHz}$		-	18	-	pF

Note

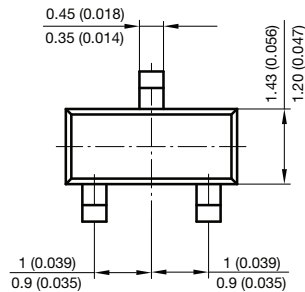
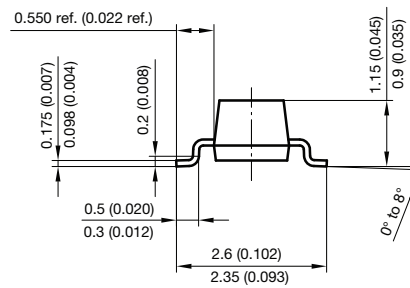
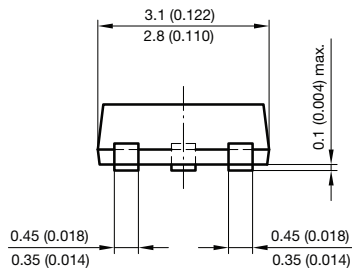
- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 2 or pin 2 to 1; pin 3 not connected)

ELECTRICAL CHARACTERISTICS GSOT36C						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_R = 1 \mu\text{A}$	V_{RWM}	36.5	-	-	V
Reverse current	at $V_R = 36.5 \text{ V}$	I_R	-	-	1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	39.5	43.7	-	V
Reverse clamping voltage	at $I_{\text{PP}} = 1 \text{ A}$	V_C	-	50	60	V
	at $I_{\text{PP}} = I_{\text{PPM}} = 3.5 \text{ A}$		-	60	72	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	26	33	pF
	at $V_R = 18 \text{ V}$; $f = 1 \text{ MHz}$		-	10	-	pF

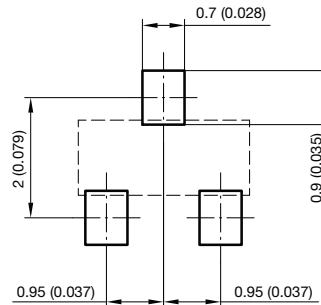
Note

- Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 to 2 or pin 2 to 1; pin 3 not connected)

PACKAGE DIMENSIONS in millimeters (inches): **SOT-23**

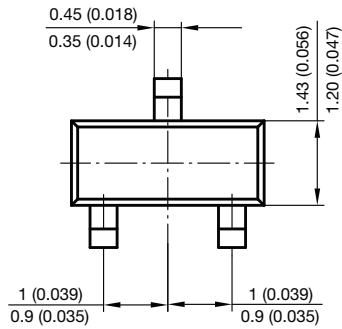
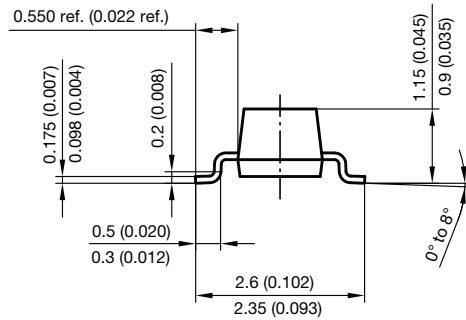
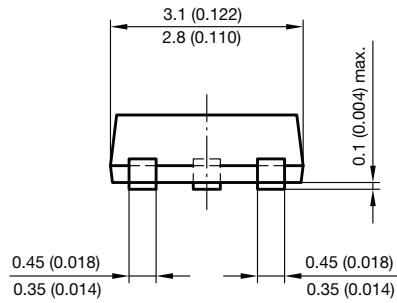


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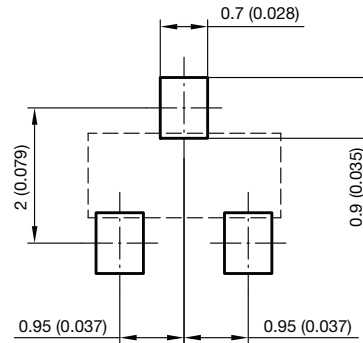


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PACKAGE DIMENSIONS in millimeters (inches)

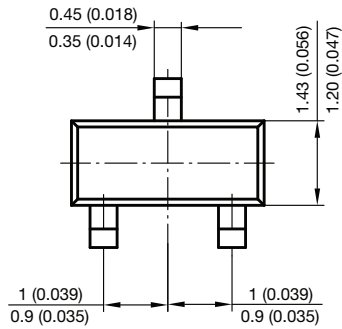
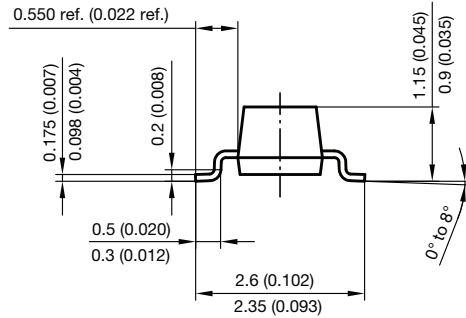
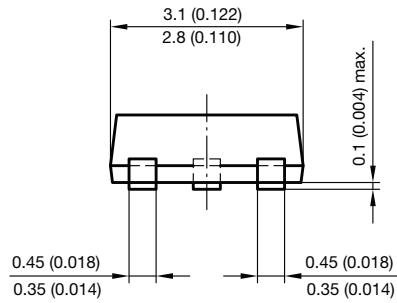


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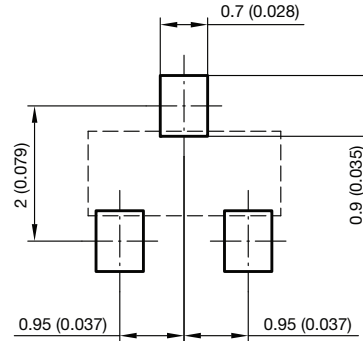


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PACKAGE DIMENSIONS in millimeters (inches)



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